NSN 5962-01-264-5234



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-264-5234 **Body Length:** 0.358 inches **Body Width:** 0.358 inches **Body Height:** 0.100 inches **Maximum Power Dissipation Rating:** 1.04 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmable and 3-state output and monolithic **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** C-4 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.3 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 55.00 nanoseconds propagation delay time, low to high level output and 55.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 leadless Shelf Life: N/a

Demilitarization:

Unit Of Measure:

Yes - demil/mli

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